

MC33269, NCV33269

Voltage Regulator - Adjustable Output, Low Dropout

800 mA

The MC33269/NCV33269 series are low dropout, medium current, fixed and adjustable, positive voltage regulators specifically designed for use in low input voltage applications. These devices offer the circuit designer an economical solution for precision voltage regulation, while keeping power losses to a minimum.

The regulator consists of a 1.0 V dropout composite PNP-NPN pass transistor, current limiting, and thermal shutdown.

Features

- 3.3 V, 3.5 V, 5.0 V, 12 V and Adjustable Versions
2.85 V version available as MC34268
- Space Saving DPAK, SO-8 and SOT-223 Power Packages
- 1.0 V Dropout
- Output Current in Excess of 800 mA
- Thermal Protection
- Short Circuit Protection
- Output Trimmed to 1.0% Tolerance
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

DEVICE TYPE/NOMINAL OUTPUT VOLTAGE

MC33269D	Adj	MC33269T-3.5	3.5 V
NCV33269D*	Adj	MC33269D-5.0	5.0 V
MC33269DT	Adj	MC33269DT-5.0	5.0 V
NCV33269DTRK*	Adj	NCV33269DT-5.0*	5.0 V
MC33269T	Adj	NCV33269DTRK-5.0*	5.0 V
MC33269D-3.3	3.3 V	MC33269T-5.0	5.0 V
MC33269DT-3.3	3.3 V	MC33269D-012	12 V
NCV33269DTRK-3.3*	3.3 V	MC33269DT-012	12 V
MC33269T-3.3	3.3 V	NCV33269DTRK-012*	12 V
MC33269ST-3.3	3.3 V	MC33269T-012	12 V

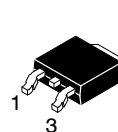
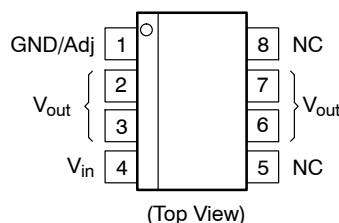
*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.



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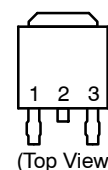
<http://onsemi.com>

SO-8
D SUFFIX
CASE 751

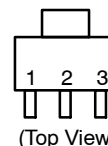


DPAK
DT SUFFIX
CASE 369C

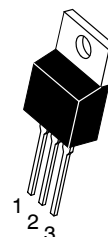
1. GND/Adj
2. V_{out}
3. V_{in}



SOT-223
ST SUFFIX
CASE 318E

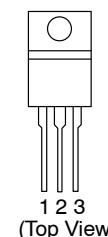


Heatsink surface (shown as terminal 4 in case outline drawing) is connected to Pin 2.



TO-220AB
T SUFFIX
CASE 221AB

1. GND/Adj
2. V_{out}
3. V_{in}



Heatsink surface (shown as terminal 4 in case outline drawing) is connected to Pin 2.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 8 of this data sheet.

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Input Voltage	V_{in}	20	V
Power Dissipation			
Case 369C (DPAK) $T_A = 25^\circ\text{C}$	P_D	Internally Limited	W
Thermal Resistance, Junction-to-Ambient	θ_{JA}	92	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	θ_{JC}	6.0	$^\circ\text{C/W}$
Case 751 (SO-8) $T_A = 25^\circ\text{C}$	P_D	Internally Limited	W
Thermal Resistance, Junction-to-Ambient	θ_{JA}	160	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	θ_{JC}	25	$^\circ\text{C/W}$
Case 221A (TO-220) $T_A = 25^\circ\text{C}$	P_D	Internally Limited	W
Thermal Resistance, Junction-to-Ambient	θ_{JA}	65	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	θ_{JC}	5.0	$^\circ\text{C/W}$
Case 318E (SOT-223) $T_A = 25^\circ\text{C}$	P_D	Internally Limited	W
Thermal Resistance, Junction-to-Ambient	θ_{JA}	156	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Case	θ_{JC}	15	$^\circ\text{C/W}$
Operating Die Junction Temperature Range	T_J	-40 to +150	$^\circ\text{C}$
Operating Ambient Temperature Range MC33269 NCV33269	T_A	-40 to +125 -40 to +125	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$
Electrostatic Discharge Sensitivity (ESD) Human Body Model (HBM) Machine Model (MM)	ESD	4000 400	V

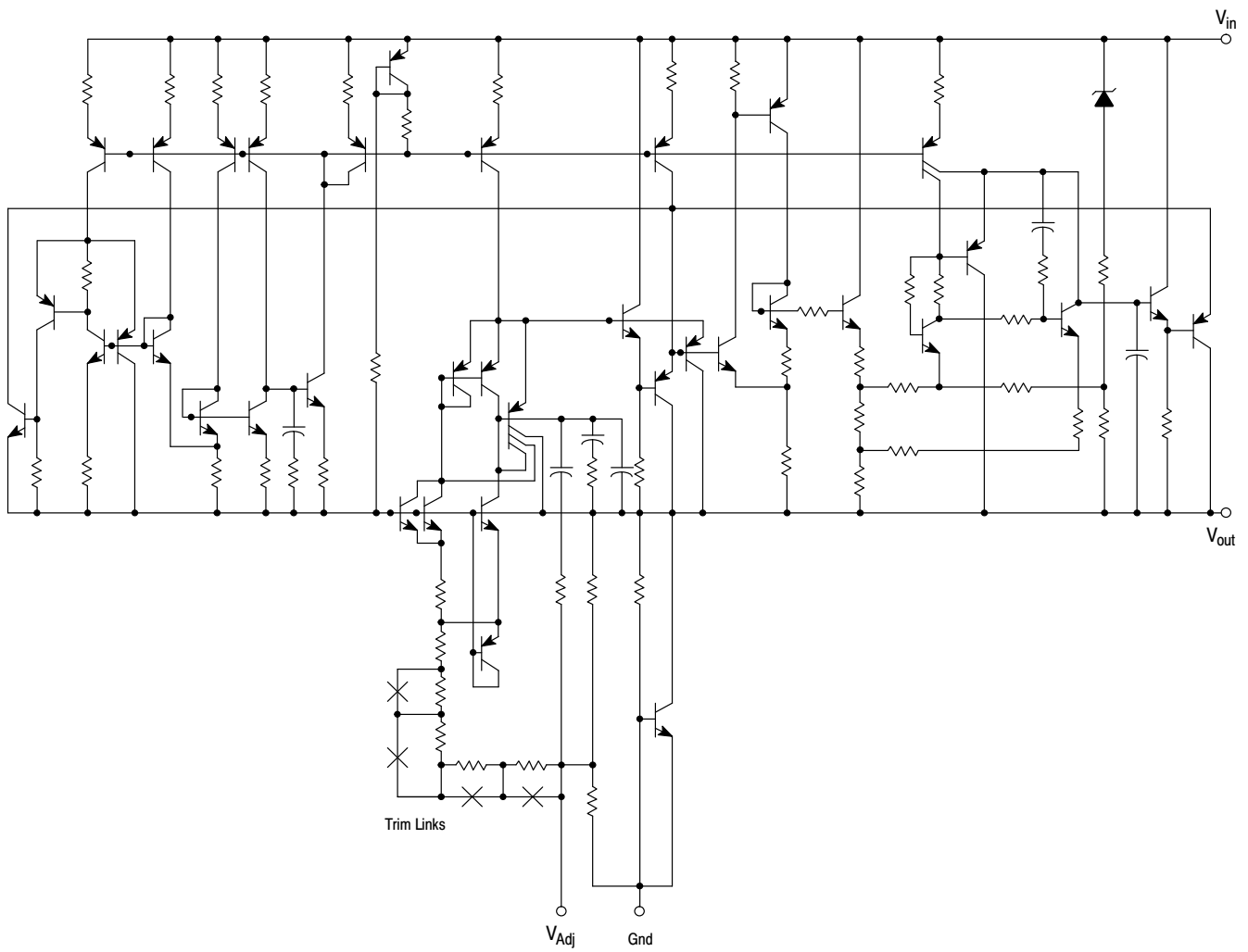
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS ($C_O = 10 \mu\text{F}$, $T_A = 25^\circ\text{C}$, for min/max values $T_A = -40^\circ\text{C}$ to $+125^\circ\text{C}$, unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
Output Voltage ($I_{out} = 10 \text{ mA}$, $T_A = 25^\circ\text{C}$) 3.3 Suffix ($V_{CC} = 5.3 \text{ V}$) 3.5 Suffix ($V_{CC} = 5.5 \text{ V}$) 5.0 Suffix ($V_{CC} = 7.0 \text{ V}$) 12 Suffix ($V_{CC} = 14 \text{ V}$)	V_O	3.27 3.465 4.95 11.88	3.3 3.5 5.0 12	3.33 3.535 5.05 12.12	V
Output Voltage (Line, Load and Temperature) (Note 1) ($1.25 \text{ V} \leq V_{in} - V_{out} \leq 15 \text{ V}$, $I_{out} = 500 \text{ mA}$) ($1.35 \text{ V} \leq V_{in} - V_{out} \leq 10 \text{ V}$, $I_{out} = 800 \text{ mA}$) 3.3 Suffix 3.5 Suffix 5.0 Suffix 12 Suffix	V_O	3.23 3.43 4.90 11.76	3.3 3.5 5.0 12	3.37 3.57 5.10 12.24	V
Reference Voltage for Adjustable Voltage ($I_{out} = 10 \text{ mA}$, $V_{in} - V_{out} = 2.0 \text{ V}$, $T_A = 25^\circ\text{C}$)	V_{ref}	1.235	1.25	1.265	V
Reference Voltage (Line, Load and Temperature) (Note 1) for Adjustable Voltage ($1.25 \text{ V} \leq V_{in} - V_{out} \leq 15 \text{ V}$, $I_{out} = 500 \text{ mA}$) ($1.35 \text{ V} \leq V_{in} - V_{out} \leq 10 \text{ V}$, $I_{out} = 800 \text{ mA}$)	V_{ref}	1.225	1.25	1.275	V
Line Regulation ($I_{out} = 10 \text{ mA}$, $V_{in} = [V_{out} + 1.5 \text{ V}]$ to $V_{in} = 20 \text{ V}$, $T_A = 25^\circ\text{C}$)	Reg_{line}	–	–	0.3	%
Load Regulation ($V_{in} = V_{out} + 3.0 \text{ V}$, $I_{out} = 10 \text{ mA}$ to 800 mA , $T_A = 25^\circ\text{C}$)	Reg_{load}	–	–	0.5	%
Dropout Voltage ($I_{out} = 500 \text{ mA}$) ($I_{out} = 800 \text{ mA}$)	$V_{in} - V_{out}$	– –	1.0 1.1	1.25 1.35	V
Ripple Rejection (10 V_{pp} , 120 Hz Sinewave; $I_{out} = 500 \text{ mA}$)	RR	55	–	–	dB
Current Limit ($V_{in} - V_{out} = 10 \text{ V}$)	I_{Limit}	800	–	–	mA
Quiescent Current (Fixed Output) ($1.5 \text{ V} \leq V_{out} \leq 3.5 \text{ V}$) ($5 \text{ V} \leq V_{out} \leq 12 \text{ V}$)	I_Q	– –	5.5 –	8.0 20	mA
Minimum Required Load Current Fixed Output Voltage Adjustable Voltage	I_{Load}	– 8.0	– –	0 –	mA
Adjustment Pin Current	I_{Adj}	–	–	120	μA

1. The MC33269–12, $V_{in} - V_{out}$ is limited to 8.0 V maximum, because of the 20 V maximum rating applied to V_{in} .

MC33269, NCV33269



This device contains 38 active transistors.

Figure 1. Internal Schematic



Figure 2. Dropout Voltage versus Output Load Current



Figure 3. Transient Load Regulation



Figure 4. Dropout Voltage versus Temperature

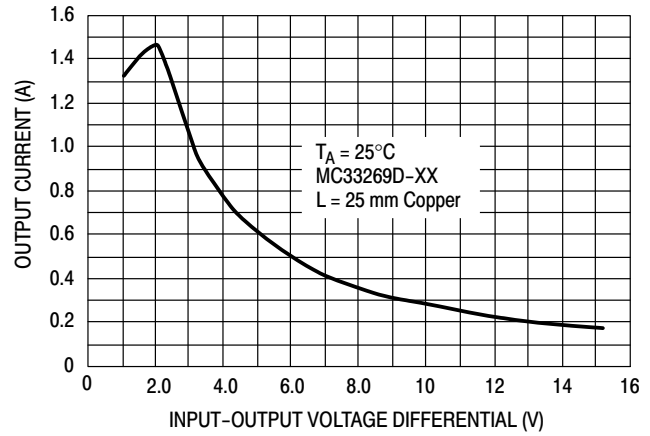


Figure 5. MC33269-XX Output DC Current versus Input-Output Differential Voltage



Figure 6. MC33269 Ripple Rejection versus Frequency

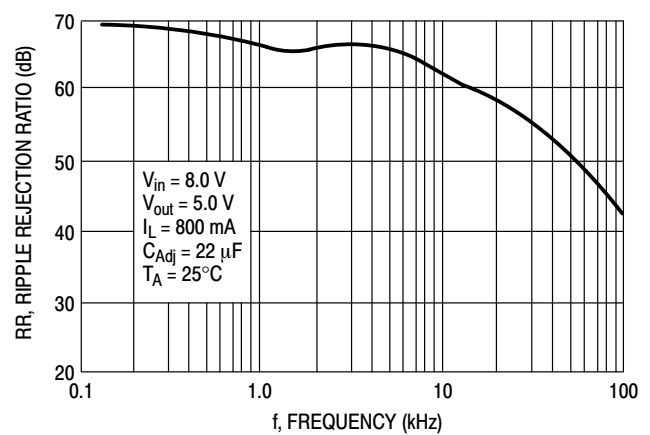


Figure 7. MC33269-ADJ Ripple Rejection versus Frequency

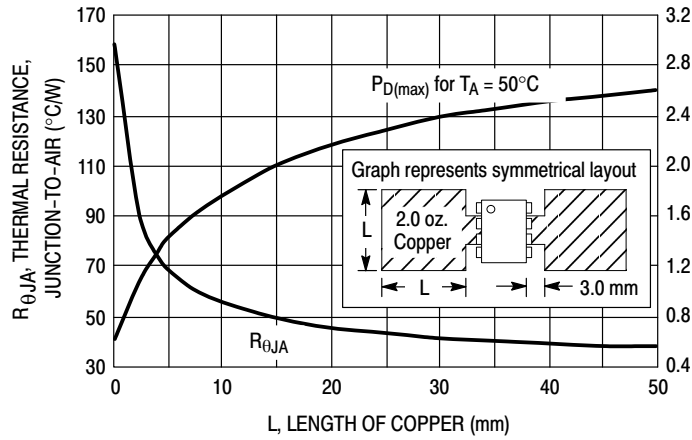


Figure 8. SOP-8 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

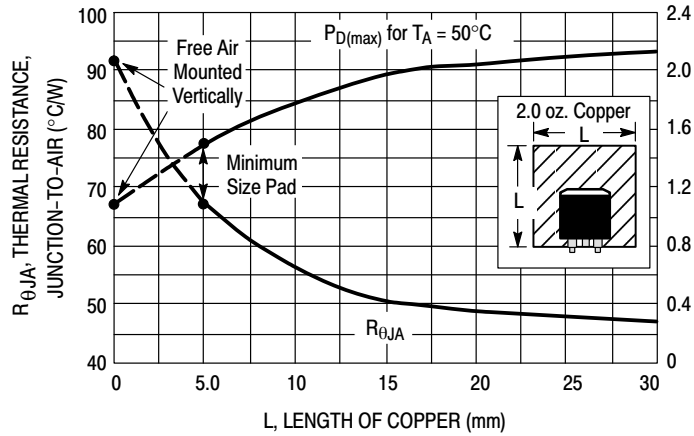


Figure 9. DPAK Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

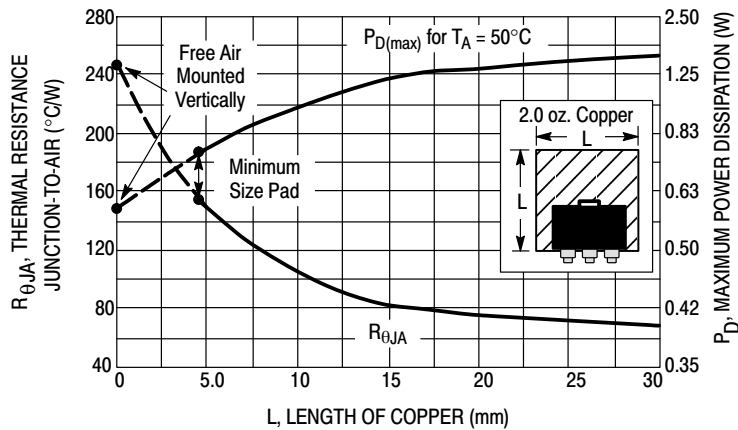


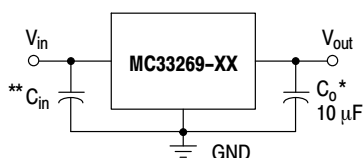
Figure 10. SOT-223 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

APPLICATIONS INFORMATION

Figures 11 through 15 are typical application circuits. The output current capability of the regulator is in excess of 800 mA, with a typical dropout voltage of less than 1.0 V. Internal protective features include current and thermal limiting.

* The MC33269 requires an external output capacitor for stability. The capacitor should be at least 10 μF with an equivalent series resistance (ESR) of less than 10 Ω but greater than 0.2 Ω over the anticipated operating temperature range. With economical electrolytic capacitors, cold temperature operation can pose a problem. As temperature decreases, the capacitance also decreases and the ESR increases, which could cause the circuit to oscillate. Also capacitance and ESR of a solid tantalum capacitor is more stable over temperature. The use of a low ESR ceramic capacitor placed within close proximity to the output of the device could cause instability.

** An input bypass capacitor is recommended to improve transient response or if the regulator is connected to the

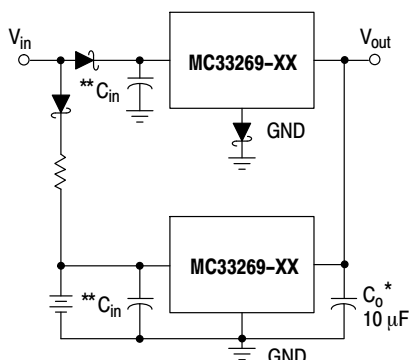


An input capacitor is not necessary for stability, however it will improve the overall performance.

Figure 11. Typical Fixed Output Application



Figure 13. Current Regulator

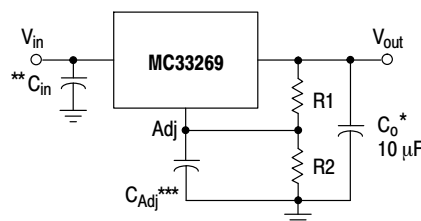


The Schottky diode in series with the ground leg of the upper regulator shifts its output voltage higher by the forward voltage drop of the diode. This will cause the lower device to remain off until the input voltage is removed.

Figure 14. Battery Backed-Up Power Supply

supply input filter with long wire lengths. This will reduce the circuit's sensitivity to the input line impedance at high frequencies. A 0.33 μF or larger tantalum, mylar, ceramic, or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with shortest possible lead or track length directly across the regulator's input terminals. **Applications should be tested over all operating conditions to insure stability.**

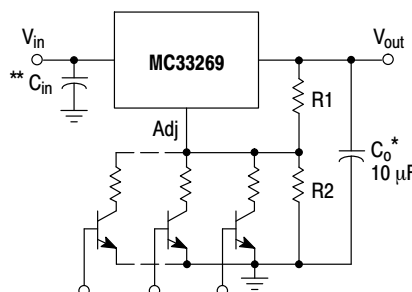
Internal thermal limiting circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated, typically at 170°C, the output is disabled. There is no hysteresis built into the thermal limiting circuit. As a result, if the device is overheating, the output will appear to be oscillating. This feature is provided to prevent catastrophic failures from accidental device overheating. **It is not intended to be used as a substitute for proper heat-sinking.**



$$V_{out} = 1.25 \left(1 + \frac{R2}{R1} \right) + I_{Adj} R2$$

***C_{Adj} is optional, however it will improve the ripple rejection. The MC34269 develops a 1.25 V reference voltage between the output and the adjust terminal. Resistor R1, operates with constant current to flow through it and resistor R2. This current should be set such that the Adjust Pin current causes negligible drop across resistor R2. The total current with minimum load should be greater than 8.0 mA.

Figure 12. Typical Adjustable Output Application



R₂ sets the maximum output voltage. Each transistor reduces the output voltage when turned on.

Figure 15. Digitally Controlled Voltage Regulator

MC33269, NCV33269

ORDERING INFORMATION

Device	Package	Shipping Information†
MC33269DG	SO-8 (Pb-Free)	98 Units / Rail
MC33269DR2G	SO-8 (Pb-Free)	2500 Units / Tape & Reel
MC33269DTG	DPAK (Pb-Free)	75 Units / Rail
MC33269DTRKG	DPAK (Pb-Free)	2500 Units / Tape & Reel
MC33269TG	TO-220 (Pb-Free)	50 Units / Rail
MC33269D-3.3G	SO-8 (Pb-Free)	98 Units / Rail
MC33269DR2-3.3G	SO-8 (Pb-Free)	2500 Units / Tape & Reel
MC33269DT-3.3G	DPAK (Pb-Free)	75 Units / Rail
MC33269DTRK-3.3G	DPAK (Pb-Free)	2500 Units / Tape & Reel
MC33269ST-3.3T3G	SOT-223 (Pb-Free)	4000 Units / Tape & Reel
MC33269T-3.3G	TO-220 (Pb-Free)	50 Units / Rail
MC33269T-3.5G	TO-220 (Pb-Free)	50 Units / Rail
MC33269D-5.0G	SO-8 (Pb-Free)	98 Units / Rail
MC33269DR2-5.0G	SO-8 (Pb-Free)	2500 Units / Tape & Reel
MC33269DT-5.0G	DPAK (Pb-Free)	75 Units / Rail
NCV33269DT-5.0G*	DPAK (Pb-Free)	75 Units / Rail
MC33269DTRK-5.0G	DPAK (Pb-Free)	2500 Units / Tape & Reel
MC33269T-5.0G	TO-220 (Pb-Free)	50 Units / Rail
MC33269D-012G	SO-8 (Pb-Free)	98 Units / Rail
MC33269DR2-012G	SO-8 (Pb-Free)	2500 Units / Tape & Reel
MC33269DT-012G	DPAK (Pb-Free)	75 Units / Rail
MC33269DTRK-012G	DPAK (Pb-Free)	2500 Units / Tape & Reel
MC33269T-012G	TO-220 (Pb-Free)	50 Units / Rail
NCV33269DR2G*	SO-8 (Pb-Free)	2500 Units / Tape & Reel
NCV33269DTRKG*	DPAK (Pb-Free)	2500 Units / Tape & Reel
NCV33269DTRK3.3G*	DPAK (Pb-Free)	2500 Units / Tape & Reel
NCV33269DTRK5.0G*	DPAK (Pb-Free)	2500 Units / Tape & Reel
NCV33269DTRK-12G*	DPAK (Pb-Free)	2500 Units / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

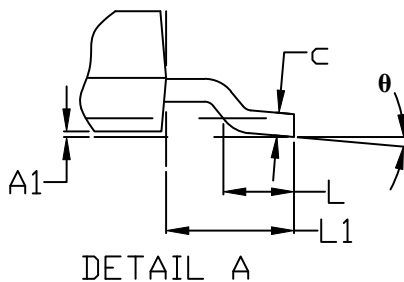
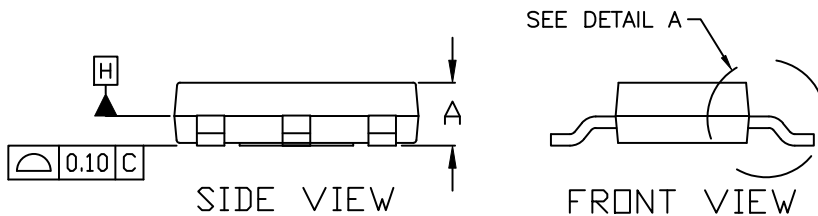
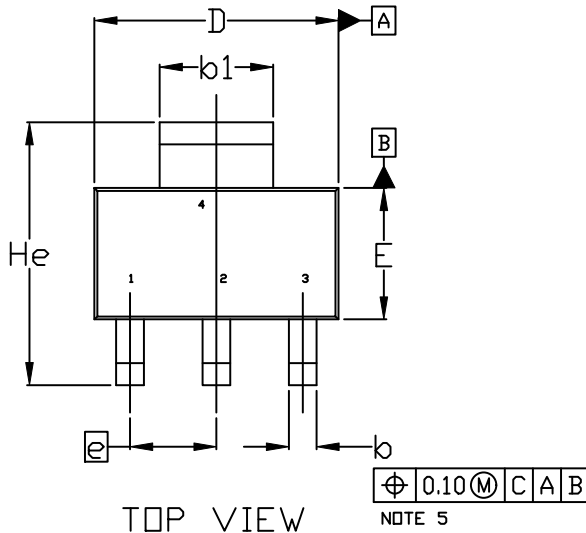
*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.



SCALE 1:1

SOT-223 (TO-261)
CASE 318E-04
ISSUE R

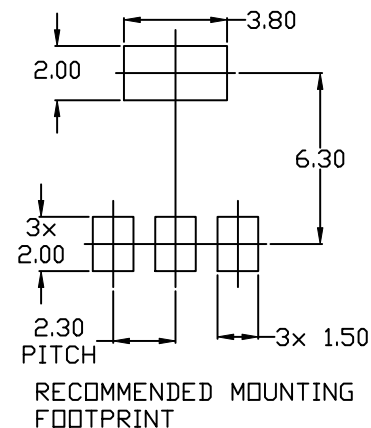
DATE 02 OCT 2018



NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D & E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.200MM PER SIDE.
4. DATUMS A AND B ARE DETERMINED AT DATUM H.
5. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
6. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS b AND b1.

MILLIMETERS			
DIM	MIN.	NOM.	MAX.
A	1.50	1.63	1.75
A1	0.02	0.06	0.10
b	0.60	0.75	0.89
b1	2.90	3.06	3.20
c	0.24	0.29	0.35
D	6.30	6.50	6.70
E	3.30	3.50	3.70
e	2.30 BSC		
L	0.20	---	---
L1	1.50	1.75	2.00
He	6.70	7.00	7.30
θ	0°	---	10°



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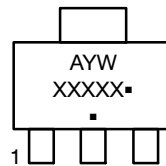
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SOT-223 (TO-261)
CASE 318E-04
ISSUE R

DATE 02 OCT 2018

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR	STYLE 2: PIN 1. ANODE 2. CATHODE 3. NC 4. CATHODE	STYLE 3: PIN 1. GATE 2. DRAIN 3. SOURCE 4. DRAIN	STYLE 4: PIN 1. SOURCE 2. DRAIN 3. GATE 4. DRAIN	STYLE 5: PIN 1. DRAIN 2. GATE 3. SOURCE 4. GATE
STYLE 6: PIN 1. RETURN 2. INPUT 3. OUTPUT 4. INPUT	STYLE 7: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 4. CATHODE	STYLE 8: CANCELLED	STYLE 9: PIN 1. INPUT 2. GROUND 3. LOGIC 4. GROUND	STYLE 10: PIN 1. CATHODE 2. ANODE 3. GATE 4. ANODE
STYLE 11: PIN 1. MT 1 2. MT 2 3. GATE 4. MT 2	STYLE 12: PIN 1. INPUT 2. OUTPUT 3. NC 4. OUTPUT	STYLE 13: PIN 1. GATE 2. COLLECTOR 3. EMITTER 4. COLLECTOR		

**GENERIC
MARKING DIAGRAM***



A = Assembly Location
 Y = Year
 W = Work Week
 XXXXX = Specific Device Code
 ■ = Pb-Free Package

(Note: Microdot may be in either location)
 *This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

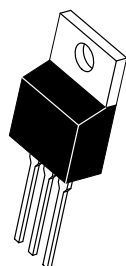
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MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

ON Semiconductor®



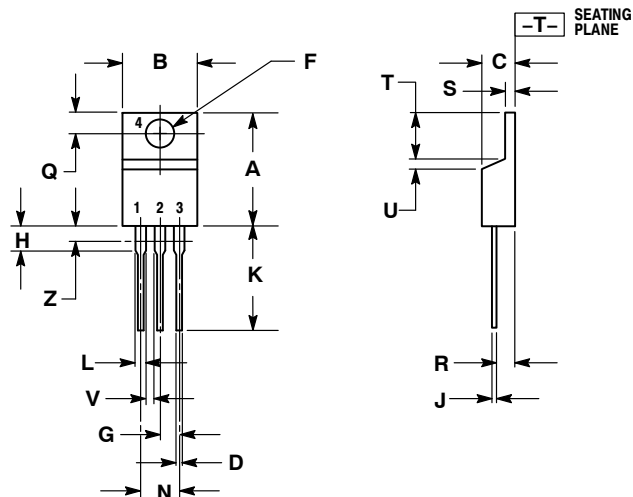
SCALE 1:1

TO-220, SINGLE GAUGE

CASE 221AB-01

ISSUE A

DATE 16 NOV 2010



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.
4. PRODUCT SHIPPED PRIOR TO 2008 HAD DIMENSIONS
S = 0.045 - 0.055 INCHES (1.143 - 1.397 MM)

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.020	0.024	0.508	0.61
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

STYLE 1:

- PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 2:

- PIN 1. BASE
2. EMITTER
3. COLLECTOR
4. EMITTER

STYLE 3:

- PIN 1. CATHODE
2. ANODE
3. GATE
4. ANODE

STYLE 4:

- PIN 1. MAIN TERMINAL 1
2. MAIN TERMINAL 2
3. GATE
4. MAIN TERMINAL 2

STYLE 5:

- PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN

STYLE 6:

- PIN 1. ANODE
2. CATHODE
3. ANODE
4. CATHODE

STYLE 7:

- PIN 1. CATHODE
2. ANODE
3. CATHODE
4. ANODE

STYLE 8:

- PIN 1. CATHODE
2. ANODE
3. EXTERNAL TRIP/DELAY
4. ANODE

STYLE 9:

- PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 10:

- PIN 1. GATE
2. SOURCE
3. DRAIN
4. SOURCE

STYLE 11:

- PIN 1. DRAIN
2. SOURCE
3. GATE
4. SOURCE

DOCUMENT NUMBER: 98AON23085D

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DESCRIPTION: TO-220, SINGLE GAUGE

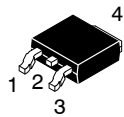
PAGE 1 OF 1

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

ON Semiconductor®

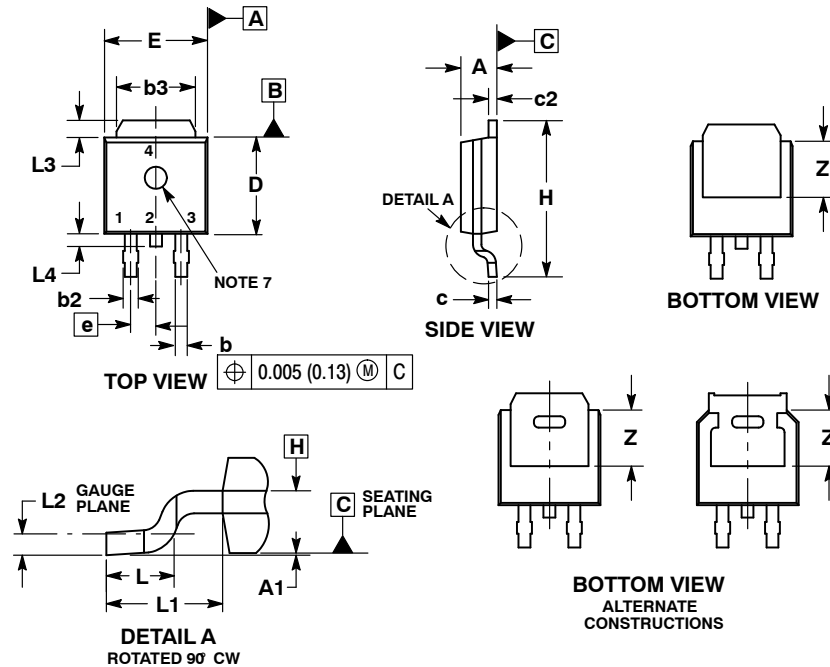
ON



SCALE 1:1

DPAK (SINGLE GAUGE) CASE 369C ISSUE F

DATE 21 JUL 2015

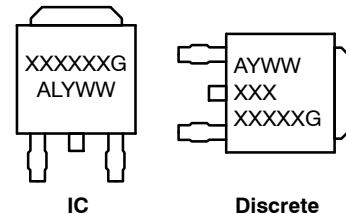


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
7. OPTIONAL MOLD FEATURE.

DIM	MIN	MAX	MIN	MAX
A	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090 BSC		2.29 BSC	
H	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114 REF		2.90 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4	---	0.040	---	1.01
Z	0.155	---	3.93	---

GENERIC MARKING DIAGRAM*

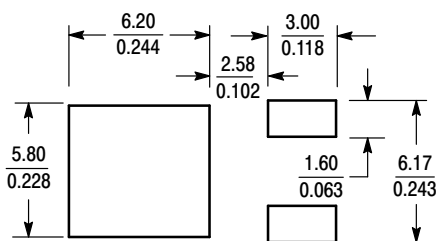


XXXXXX = Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
WW = Work Week
G = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking.

- STYLE 1:**
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR
- STYLE 2:**
PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN
- STYLE 3:**
PIN 1. ANODE
2. CATHODE
3. ANODE
4. CATHODE
- STYLE 4:**
PIN 1. CATHODE
2. ANODE
3. GATE
4. ANODE
- STYLE 5:**
PIN 1. GATE
2. ANODE
3. CATHODE
4. ANODE
- STYLE 6:**
PIN 1. MT1
2. MT2
3. GATE
4. MT2
- STYLE 7:**
PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR
- STYLE 8:**
PIN 1. N/C
2. CATHODE
3. ANODE
4. CATHODE
- STYLE 9:**
PIN 1. ANODE
2. CATHODE
3. RESISTOR ADJUST
4. CATHODE
- STYLE 10:**
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. ANODE

SOLDERING FOOTPRINT*



SCALE 3:1 (mm inches)

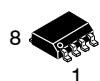
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	DPAK (SINGLE GAUGE)	PAGE 1 OF 1

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MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

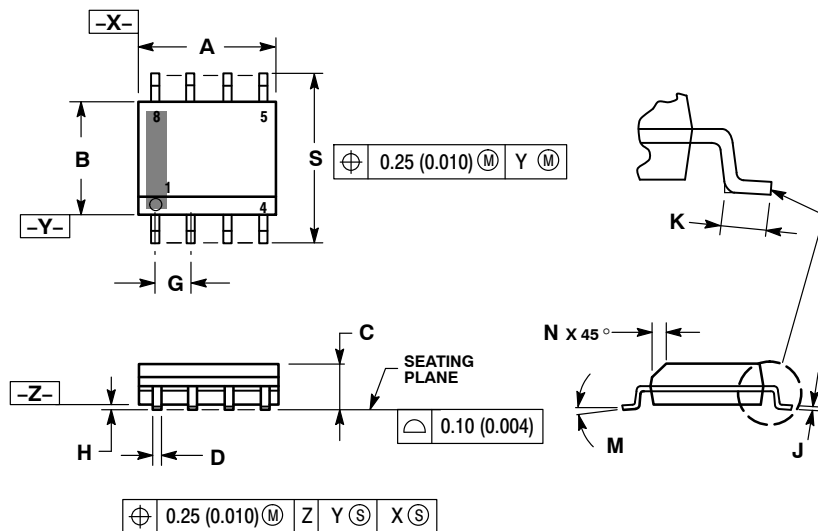
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SCALE 1:1

SOIC-8 NB
CASE 751-07
ISSUE AK

DATE 16 FEB 2011

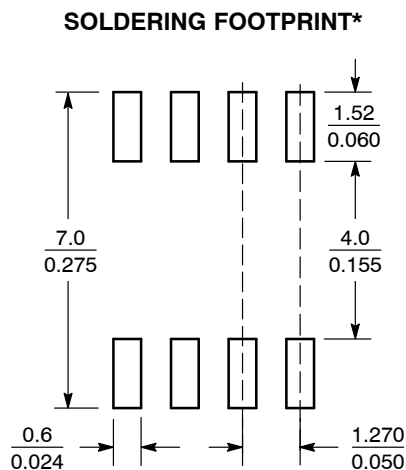


NOTES:

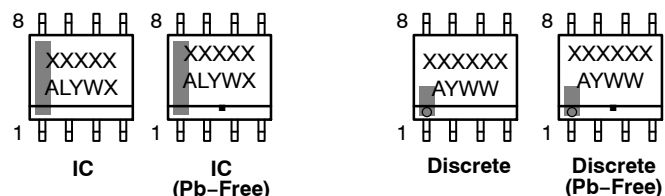
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

GENERIC MARKING DIAGRAM*



SCALE 6:1 (mm/inches)



XXXXXX = Specific Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
W = Work Week
■ = Pb-Free Package

XXXXXX = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
■ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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SOIC-8 NB
CASE 751-07
ISSUE AK

DATE 16 FEB 2011

STYLE 1: PIN 1. EMITTER 2. COLLECTOR 3. COLLECTOR 4. EMITTER 5. EMITTER 6. BASE 7. BASE 8. EMITTER	STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 5. BASE, #2 6. EMITTER, #2 7. BASE, #1 8. EMITTER, #1	STYLE 3: PIN 1. DRAIN, DIE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. GATE, #2 6. SOURCE, #2 7. GATE, #1 8. SOURCE, #1	STYLE 4: PIN 1. ANODE 2. ANODE 3. ANODE 4. ANODE 5. ANODE 6. ANODE 7. ANODE 8. COMMON CATHODE
STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN 4. DRAIN 5. GATE 6. GATE 7. SOURCE 8. SOURCE	STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE	STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd	STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 8. COLLECTOR, #1
STYLE 9: PIN 1. EMITTER, COMMON 2. COLLECTOR, DIE #1 3. COLLECTOR, DIE #2 4. EMITTER, COMMON 5. EMITTER, COMMON 6. BASE, DIE #2 7. BASE, DIE #1 8. EMITTER, COMMON	STYLE 10: PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND 5. GROUND 6. BIAS 2 7. INPUT 8. GROUND	STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 8. DRAIN 1	STYLE 12: PIN 1. SOURCE 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 13: PIN 1. N.C. 2. SOURCE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN	STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN	STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3. ANODE 1 4. ANODE 1 5. CATHODE, COMMON 6. CATHODE, COMMON 7. CATHODE, COMMON 8. CATHODE, COMMON	STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2 4. BASE, DIE #2 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 7. COLLECTOR, DIE #1 8. COLLECTOR, DIE #1
STYLE 17: PIN 1. VCC 2. V2OUT 3. V1OUT 4. TXE 5. RXE 6. VEE 7. GND 8. ACC	STYLE 18: PIN 1. ANODE 2. ANODE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. CATHODE 8. CATHODE	STYLE 19: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1	STYLE 20: PIN 1. SOURCE (N) 2. GATE (N) 3. SOURCE (P) 4. GATE (P) 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3. CATHODE 3 4. CATHODE 4 5. CATHODE 5 6. COMMON ANODE 7. COMMON ANODE 8. CATHODE 6	STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3. COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND	STYLE 23: PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT	STYLE 24: PIN 1. BASE 2. EMITTER 3. COLLECTOR/ANODE 4. COLLECTOR/ANODE 5. CATHODE 6. CATHODE 7. COLLECTOR/ANODE 8. COLLECTOR/ANODE
STYLE 25: PIN 1. VIN 2. N/C 3. REXT 4. GND 5. IOUT 6. IOUT 7. IOUT 8. IOUT	STYLE 26: PIN 1. GND 2. dv/dt 3. ENABLE 4. ILIMIT 5. SOURCE 6. SOURCE 7. SOURCE 8. VCC	STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN	STYLE 28: PIN 1. SW_TO_GND 2. DASIC_OFF 3. DASIC_SW_DET 4. GND 5. V_MON 6. VBULK 7. VBULK 8. VIN
STYLE 29: PIN 1. BASE, DIE #1 2. EMITTER, #1 3. BASE, #2 4. EMITTER, #2 5. COLLECTOR, #2 6. COLLECTOR, #2 7. COLLECTOR, #1 8. COLLECTOR, #1	STYLE 30: PIN 1. DRAIN 1 2. DRAIN 1 3. GATE 2 4. SOURCE 2 5. SOURCE 1/DRAIN 2 6. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 8. GATE 1		

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